Product Introduction

Chip Multilayer RF Ceramic Inductors Add New Options for High-Frequency Applications.

Features :

- High Q and high reliability and ceramic material.
- To prevent EMI interference noises between electronic circuits.

Applications :

- Display Monitor, Gaming Machine,
- Notebook Computer, Disc Drive Unit(CD/DVD),
- Inkjet Printer, Hard Disk Drive, Copying Machine,
- Video Tape Recorder, DVD Player, Video Camera,
- Color TV, Digital Still Camera, Car Electronics, Lowest EMI.

Ceramic materials and process technologies have allowed Token to add magnetics portfolio with a new series of multilayer high-frequency ceramic inductors. The Token (TRMF) series inductors are aimed at signal shaping and RF filtering applications in a wide range of electronic systems. Target end products include remote controls, high-end video processing equipment, set-top boxes, cell phones, pagers, keyless entry systems, wireless and wire line networks, and cable modems.

Standard inductance options for the (TRMF) series range from 1 nH to 100 nH. Available tolerances are ±0.3nH, ±5%, and ±10%. Maximum DC resistance (DCR) ranges from 0.1Ω to 2.5Ω depending on inductance. In a space-saving surface-mount 0402 package measures (1 × 0.5 mm) and with 2-mil (0.5 mm) height profile. 0402, 0603, and 0805 package size is available.

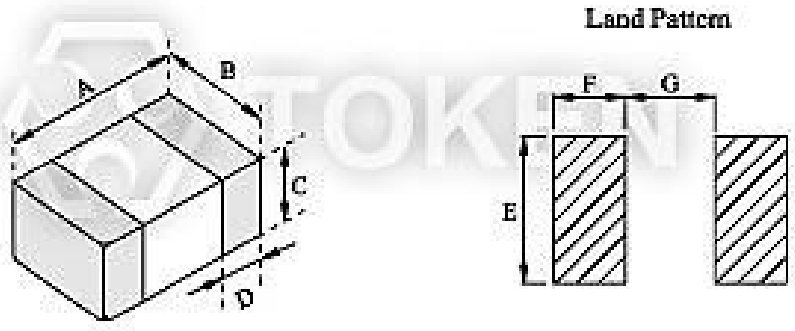
(TRMF) inductors feature a high Q rating and minimum self-resonant frequency ranges from 0.6 GHz to 10 GHz. Designed for reliable operation in high-frequency applications, (TRMF) inductors are rated for currents from 100 mA to 500 mA. Their surface-mount packaging is solder able by reflow or wave methods and specified for a wide operating temperature range of -55℃ to +125℃.

The (TRMF) series is fully RoHS compliant and is supplied in tape and reel packaging ready for use with automated assembly processes. Contact us with your specific needs. For more information, please link to Token official website "RF Inductors".

Configurations & Dimensions

Configurations & Dimensions (unit: mm) (TRMF)

Type	A	B	C	D	E	F	G
TRMF100505 (0402)	1.0 ± 0.1	0.5 ± 0.1	0.5 ± 0.1	0.1(min)	0.5	0.45	0.5
TRMF160808 (0603)	1.6 ± 0.2	0.8 ± 0.2	0.8 ± 0.2	0.3 ± 0.2	0.7	0.70	0.7
TRMF201209 (0805)	2.0 ± 0.2	1.2 ± 0.2	0.9 ± 0.2	0.5 ± 0.3	1.0	0.80	1.0



RF Surface Mount (TRMF) Dimensions

Electrical Characteristics

Electrical Characteristics (TRMF100505) - EIA 0402

Part Number	Inductance (nH)	Tolerance	Quality Factor /Min	L/Q Freq. (MHz)	Q (typical) Frequency (MHz)			Resistance DC/Max (Ohm)	Self-Resonant Frequency /Min.(GHz)	Current DC/Max (mA)
					100	500	800			
TRMF100505 - 1N0*	1.0	± 0.3nH	8	100	11	33	37	0.12	10.0	300
TRMF100505 - 1N2*	1.2	± 0.3nH	8	100	11	29	26	0.12	10.0	300
TRMF100505 - 1N5*	1.5	± 0.3nH	8	100	12	29	40	0.13	6.00	300
TRMF100505 - 1N8*	1.8	± 0.3nH	8	100	11	26	34	0.14	6.00	300
TRMF100505 - 2N2*	2.2	± 0.3nH	8	100	11	26	36	0.16	6.00	300
TRMF100505 - 2N7*	2.7	± 0.3nH	8	100	12	29	38	0.17	6.00	300
TRMF100505 - 3N3*	3.3	±0.3nH,±10%	8	100	11	28	37	0.19	6.00	300
TRMF100505 - 3N9*	3.9	±0.3nH,±10%	8	100	11	26	32	0.22	4.00	300
TRMF100505 - 4N7*	4.7	±0.3nH,±10%	8	100	12	28	37	0.24	4.00	300
TRMF100505 - 5N6*	5.6	±0.3nH,±10%	8	100	11	26	35	0.27	4.00	300
TRMF100505 - 6N8*	6.8	±5%,±10%	8	100	11	26	34	0.32	3.90	300
TRMF100505 - 8N2*	8.2	±5%,±10%	8	100	12	26	34	0.37	3.50	300
TRMF100505 - 10N*	10	±5%,±10%	8	100	11	25	31	0.42	3.20	300
TRMF100505 - 12N*	12	±5%,±10%	8	100	11	25	31	0.50	2.60	300
TRMF100505 - 15N*	15	±5%,±10%	8	100	11	24	30	0.55	2.30	300
TRMF100505 - 18N*	18	±5%,±10%	8	100	11	24	30	0.65	2.00	300
TRMF100505 - 22N*	22	±5%,±10%	8	100	12	24	30	0.80	1.60	300
TRMF100505 - 27N*	27	±5%,±10%	8	100	11	24	28	0.90	1.40	300
TRMF100505 - 33N*	33	±5%,±10%	8	100	12	23	26	1.00	1.20	200
TRMF100505 - 39N*	39	±5%,±10%	8	100	11	21	24	1.20	1.10	150
TRMF100505 - 47N*	47	±5%,±10%	8	100	11	21	23	1.30	0.90	150
TRMF100505 - 56N*	56	±5%,±10%	8	100	12	21	21	2.00	0.75	150
TRMF100505 - 68N*	68	±5%,±10%	8	100	11	19	19	2.20	0.75	100
TRMF100505 - 82N*	82	±5%,±10%	8	100	10	19	16	2.50	0.60	100
TRMF100505 - R10*	100	±5%,±10%	8	100	10	18	-	2.50	0.60	100

- **Note: Measuring Equipment: HP-4291B + 16192A**
  Storage Temperature: 25±3℃; Humidity<80% RH

Electrical Characteristics (TRMF160808) - EIA 0603

Part Number	Inductance (nH)	Tolerance	Quality Factor /Min	L/Q Freq. (MHz)	Q (typical) Frequency (MHz)			Resistance DC/Max (Ohm)	Self-Resonant Frequency /Min.(GHz)	Current DC/Max (mA)
					100	500	800			
TRMF160808 - 1N0*	1.0	±0.3nH	8	100	15	36	49	0.10	6.0	500
TRMF160808 - 1N2*	1.2	±0.3nH	8	100	15	36	49	0.10	6.0	500
TRMF160808 - 1N5*	1.5	±0.3nH	8	100	14	34	47	0.10	6.0	500
TRMF160808 - 1N8*	1.8	±0.3nH	8	100	17	40	55	0.10	6.0	500
TRMF160808 - 2N2*	2.2	±0.3nH	8	100	15	38	49	0.10	6.0	500
TRMF160808 - 2N7*	2.7	±0.3nH	8	100	14	37	48	0.10	6.0	500
TRMF160808 - 3N3*	3.3	±0.3nH,±10%	10	100	16	40	51	0.13	6.0	500
TRMF160808 - 3N9*	3.9	±0.3nH,±10%	10	100	14	36	48	0.15	6.0	500
TRMF160808 - 4N7*	4.7	±0.3nH,±10%	10	100	14	37	48	0.20	4.0	500
TRMF160808 - 5N6*	5.6	±0.3nH,±10%	10	100	14	36	46	0.23	4.0	500
TRMF160808 - 6N8*	6.8	±5%,±10%	10	100	15	37	48	0.25	3.75	500
TRMF160808 - 8N2*	8.2	±5%,±10%	10	100	16	39	50	0.28	3.30	500
TRMF160808 - 10N*	10	±5%,±10%	12	100	16	37	47	0.30	3.0	300
TRMF160808 - 12N*	12	±5%,±10%	12	100	15	36	45	0.35	2.6	300
TRMF160808 - 15N*	15	±5%,±10%	12	100	16	38	48	0.40	2.3	300
TRMF160808 - 18N*	18	±5%,±10%	12	100	17	38	47	0.45	2.0	300
TRMF160808 - 22N*	22	±5%,±10%	12	100	18	40	49	0.50	1.6	300
TRMF160808 - 27N*	27	±5%,±10%	12	100	18	40	47	0.55	1.4	300
TRMF160808 - 33N*	33	±5%,±10%	12	100	17	40	46	0.60	1.2	300
TRMF160808 - 39N*	39	±5%,±10%	12	100	19	40	46	0.65	1.1	300
TRMF160808 - 47N*	47	±5%,±10%	12	100	17	36	39	0.70	0.9	300
TRMF160808 - 56N*	56	±5%,±10%	12	100	18	36	37	0.75	0.9	300
TRMF160808 - 68N*	68	±5%,±10%	12	100	18	35	36	0.85	0.7	300
TRMF160808 - 82N*	82	±5%,±10%	12	100	18	33	29	1.00	0.6	300
TRMF160808 - R10*	100	±5%,±10%	12	100	18	28	16	1.20	0.6	300

- **Note: Measuring Equipment : HP-4291B + 16192A**
  Storage Temperature : 25±3℃ ; Humidity<80% RH

Electrical Characteristics (TRMF201209) - EIA 0805

Part Number	Inductance (nH)	Tolerance	Quality Factor /Min.	L/Q Freq (MHz)	Self-Resonant Frequency /Min.(GHz)	Resistance DC/Max (Ohm)	Current DC/Max (mA)
TRMF201209 - 1N0*	1.0	±0.3nH	10	100	>6.00	0.10	300
TRMF201209 - 1N2*	1.2	±0.3nH	10	100	>6.00	0.10	300
TRMF201209 - 1N5*	1.5	±0.3nH	10	100	>6.00	0.10	300
TRMF201209 - 1N8*	1.8	±0.3nH	10	100	>6.00	0.10	300
TRMF201209 - 2N2*	2.2	±0.3nH	10	100	>6.00	0.10	300
TRMF201209 - 2N7*	2.7	±0.3nH	12	100	>6.00	0.10	300
TRMF201209 - 3N3*	3.3	±0.3nH,±10%	12	100	>6.00	0.13	300
TRMF201209 - 3N9*	3.9	±0.3nH,±10%	12	100	5.40	0.15	300
TRMF201209 - 4N7*	4.7	±0.3nH,±10%	12	100	4.50	0.20	300
TRMF201209 - 5N6*	5.6	±0.3nH,±10%	12	100	4.00	0.23	300
TRMF201209 - 6N8*	6.80	±5%,±10%	15	100	3.65	0.25	300
TRMF201209 - 8N2*	8.2	±5%,±10%	15	100	3.00	0.28	300
TRMF201209 - 10N*	10	±5%,±10%	15	100	2.50	0.30	300
TRMF201209 - 12N*	12	±5%,±10%	15	100	2.45	0.35	300
TRMF201209 - 15N*	15	±5%,±10%	15	100	2.00	0.40	300
TRMF201209 - 18N*	18	±5%,±10%	15	100	1.75	0.45	300
TRMF201209 - 22N*	22	±5%,±10%	15	100	1.70	0.50	300
TRMF201209 - 27N*	27	±5%,±10%	15	100	1.55	0.55	300
TRMF201209 - 33N*	33	±5%,±10%	15	100	1.35	0.60	300
TRMF201209 - 39N*	39	±5%,±10%	18	100	1.30	0.65	300
TRMF201209 - 47N*	47	±5%,±10%	18	100	1.20	0.70	300
TRMF201209 - 56N*	56	±5%,±10%	18	100	1.15	0.75	300
TRMF201209 - 68N*	68	±5%,±10%	18	100	1.00	0.80	300
TRMF201209 - 82N*	82	±5%,±10%	18	100	0.85	0.90	300
TRMF201209 - R10*	100	±5%,±10%	18	100	0.73	1.00	300

- **Note: Measuring Equipment : HP-4291B + 16197A**
  Storage Temperature : 25±3℃ ; Humidity<80% RH

Order Codes

Order Codes (TRMF)

TRMF100505	-	1N2	S

Part Number
TRMF100505
TRMF160808
TRMF201209

Inductance	
1N2	1.2nH
10N	10.0nH
R10	100.00nH

Tolerance	
S	0.3nH
J	5%
K	10%
M	20%

General Information

Token Cuts Inductor Size and Cost

Token utilizes the latest technology enabling the most cost-effective designs in manufacturing inductors. The 0402, 0603, 0805, 1206, 1210, to 1812 series of RF Miniature Inductors all contain wire wound or multi-layer technology with material substrate in ceramic or ferrite cores. Thus providing economic cost with the ultimate performance demanded by today's RF applications. Inductors feature high Q factor, SRFs (self-resonant or series resonant frequency), and Idc (maximum current carrying capacity).

How to quickly search RF inductors for all of the characteristics?

Searching and comparing data sheets of inductor manufacturers can be time consuming.
Token's Parameter Sorting Search Mode allows selection of inductors based on different parameters.
To enter Searching Mode:

- By entering just the inductance value,
- By sorting parameter to narrow down searching range,
- Or by enter keyword / part number / size dimensions L*W*H to partial or exact searching.

Inductors Selection Notes:

For choke applications, the SRFs (self-resonant or series resonant frequency) is the frequency that provides the best signal blocking.

- At the SRF, impedance is at its maximum.
- At frequencies below the SRF, impedance increases with frequency.
- At frequencies above the SRF, impedance decreases with frequency.

For higher order filter or impedance matching applications, in general, the choice of inductance value typically determines the SRF and vice versa. The higher the inductance value, the lower the SRF, due to increased winding capacitance. It is more important to have a relatively flat inductance curve (constant inductance vs. frequency) near the required frequency. This suggests selecting an inductor with an SRF well above the design frequency. A rule of thumb is to select an inductor with an SRF that is a decade (10X) higher than the operating frequency.

What is Q factor? High Q leads to low insertion loss, minimizing power consumption, and narrow bandwidth. It is important if the inductor is to be used as part of an LC (oscillator) circuit or in narrow band pass applications. In general, wire wound inductors have much higher Q values than multilayer inductors of the same size and value. Token's material science and manufacturing expertise effectively bridges the gap between wire-wound performance and multi-layer inductors with its TRMF100505 (EIA 0402) and TRMI160808 (EIA 0603) series.

How does current requirement affect inductor? Higher current requires larger wire or more threads of the same wire size to keep losses and temperature rise to a minimum. Larger wire lowers the DCR and increases the Q factor. Using a ferrite core inductor with a lower turn count can achieve higher current capacity and lower DCR. Ferrite, however, may introduce new limitations such as larger variation of inductance with temperature, looser tolerances, lower Q, and reduced saturation current ratings. Token's ferrite inductors with open magnetic structures, will not saturate, even at full rated current.